

SANYO**LB1910N****FDD Spindle Motor Driver****Overview**

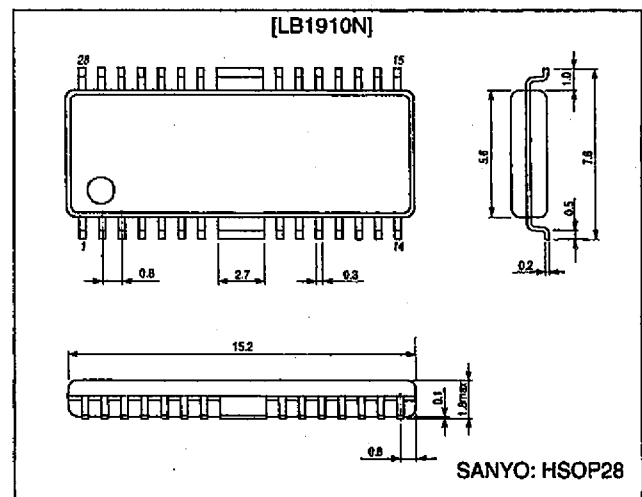
The LB1910N is a 3-phase disc drive motor driver that is optimal for use as a 3.5-inch FDD spindle motor driver.

Functions and Features

- Three-phase full-wave linear driver
- Digital speed control circuit
- Start and stop circuits (active low)
- RPM switching H: 300 rpm
 L: 360 rpm
- Current limiter circuit
- Built-in index comparator
- Thermal shutdown circuit

Package Dimensions

unit: mm

3222-HSOP28**Specifications****Absolute Maximum Ratings at Ta = 25°C**

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V_{CC} max		7.0	V
Maximum output current	I_O max1	$t \leq 0.5$ s	1.0	A
Maximum steady-state output current	I_O max2		0.7	A
Allowable power dissipation	P_d max	Independent IC	0.5	W
Operating temperature	T_{opr}		-20 to +80	°C
Storage temperature	T_{stg}		-40 to +150	°C

Allowable Operating Ranges at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	V_{CC}		4.2 to 6.5	V

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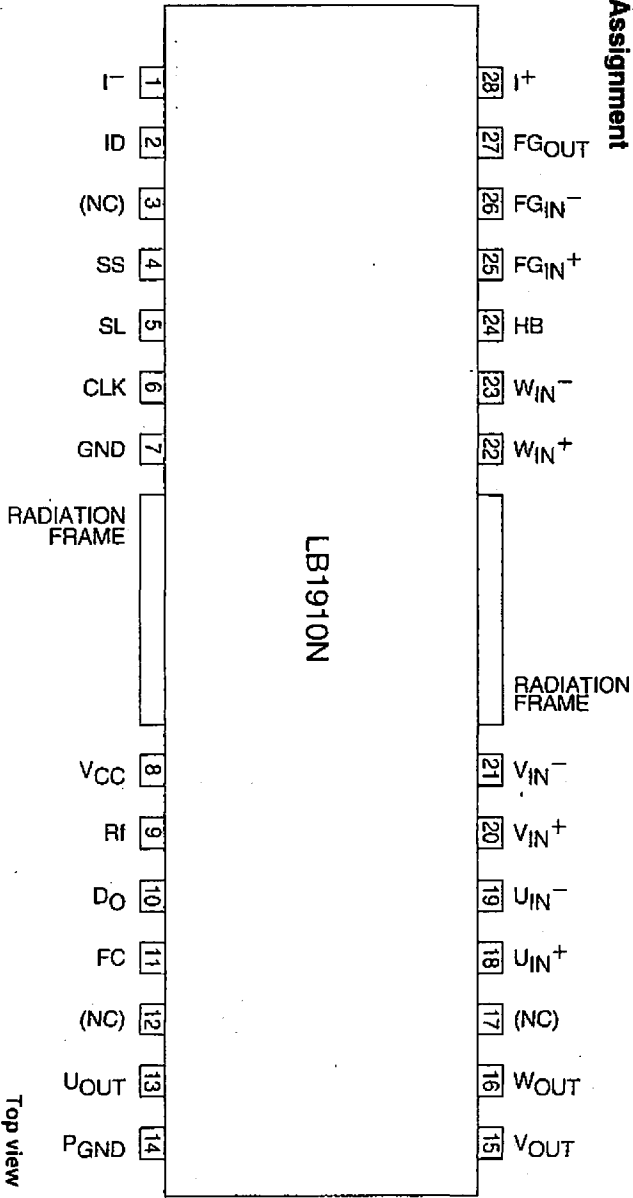
Electrical Characteristics at $T_a = 25^\circ\text{C}$, $V_{CC} = 5\text{ V}$

Parameter	Symbol	Conditions	min	typ	max	Unit
Current drain	I_{CCO}	S/S = 5 V (standby)			10	μA
	I_{CC}	S/S = 0 V (steady state)		12	18	mA
SL bias current	I_{SL}	$V_{SL} = 0\text{ V}$			10	μA
SL input low-level voltage	V_{SLL}		0		1.0	V
SL input high-level voltage	V_{SLH}		3.5		V_{CC}	V
S/S bias current	$I_{S/S}$			180	270	μA
S/S low-level voltage	$V_{S/SL}$		0		0.8	V
S/S high-level voltage	$V_{S/SH}$		3.5		V_{CC}	V
Hall amplifier input bias current	I_{HB}				10	μA
Common-mode input voltage range	V_h		1.5		$V_{CC} - 1.0$	V
Differential input voltage range	V_{dif}		50		200	mVp-p
Hall bias output voltage	V_H	$I_H = 5\text{ mA}$		0.8		V
Leakage current	I_{HL}	S/S = 5 V			± 10	μA
Output saturation voltage	V_{sat}	$I_O = 0.7\text{ A}$, sink + source		1.3	1.8	V
Output leakage current	I_{OL}				1.0	mA
Current limiter	V_{lim}		0.27	0.3	0.33	V
Control amplifier voltage gain	G_C			-7		dB
Voltage gain difference between phases	ΔG_C				± 1	dB
V/I conversion source current	I^+		9	14	19	μA
V/I conversion sink current	I^-		-9	-14	-19	μA
V/I conversion current ratio	I^+/I^-		0.8	1.0	1.2	
DSC buffer input current	I_{DSC}				1.0	μA
FG Schmitt hysteresis	ΔV_{sh}	*		50		mV
Speed discriminator counts	N			1041.5		
Discriminator operating frequency	F_D	*			1.1	MHz
Oscillator frequency range	F_{OSC}	*			1.1	MHz
Index input hysteresis	V_{IDH}		18	23	28	mV
Index input	V_{IDO}	$I_O = 2\text{ mA}$	-5	0	+5	mV
Index output low-level voltage	V_{IDL}	$I_O = 2\text{ mA}$			0.4	V
Index output leakage current	I_{IDL}				± 10	μA
FG amplifier voltage gain	G_{FG}	*		48		dB
FG amplifier input offset	V_{FGO}				± 10	mV
FG amplifier internal reference voltage	V_{FGB}		2.2	2.5	2.8	V
Thermal shutdown temperature	TSD	*	150	180		$^\circ\text{C}$
Hysteresis	ΔTSD	*		40		$^\circ\text{C}$

Note: * Items marked with an asterisk are design target values and are not measured.

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Pin Assignment



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Top view

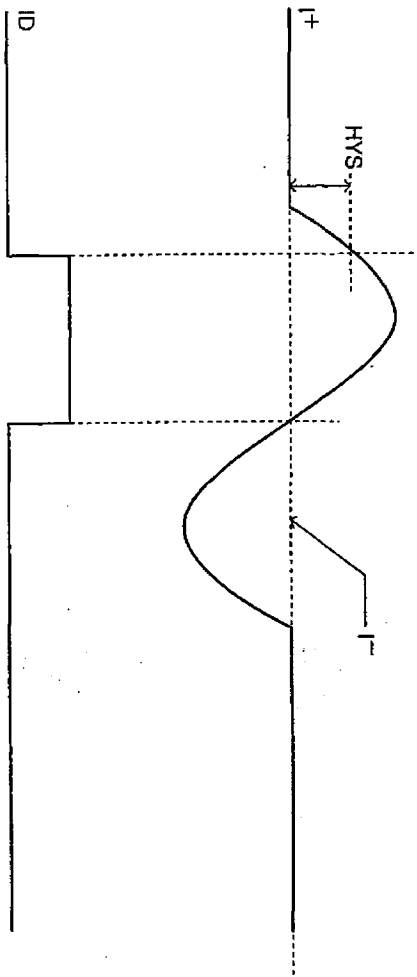
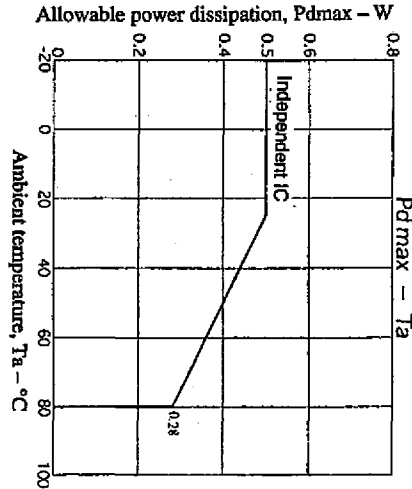
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Truth Table

	Source → sink	Hall Input		
		U	V	W
1	V phase → W phase	H	H	L
2	V phase → U phase	L	H	L
3	W phase → U phase	L	H	H
4	W phase → V phase	L	L	H
5	U phase → V phase	H	L	H
6	U phase → W phase	H	L	L

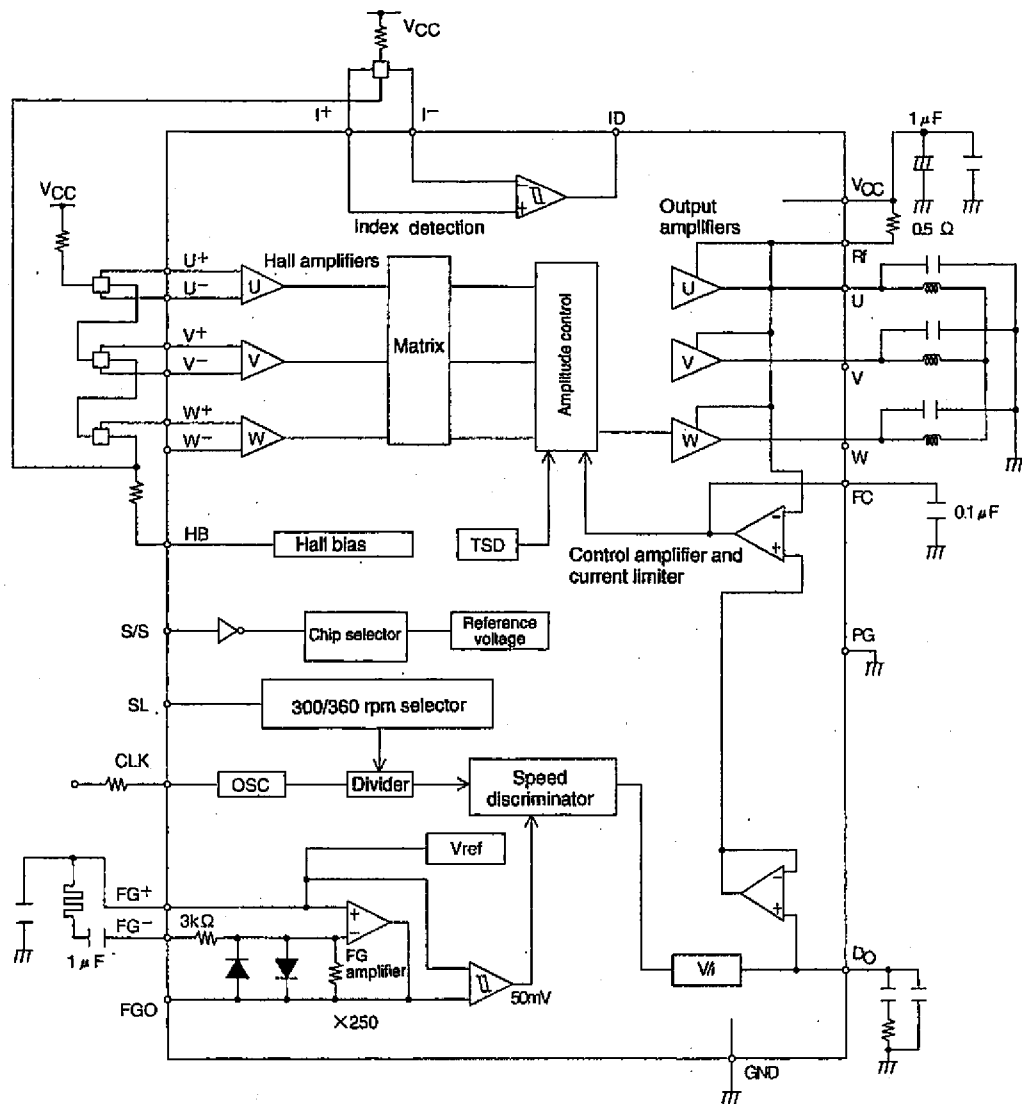
Note: Hall input high levels are defined as: U_{IN}⁺ > U_N⁻
V_{IN}⁺ > V_N⁻
W_{IN}⁺ > W_N⁻

Index Pulse Timing Chart



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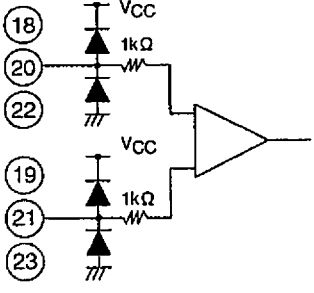
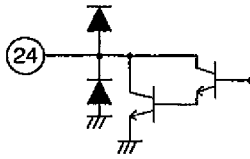
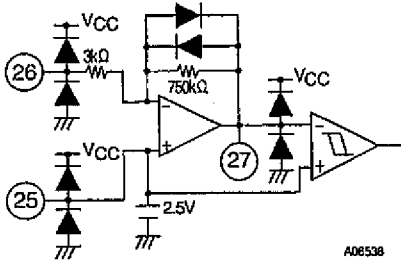
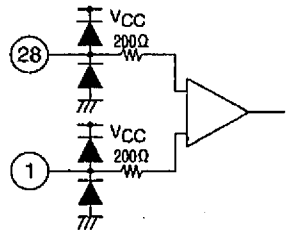
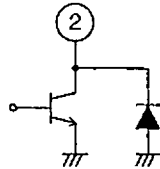
Block Diagram



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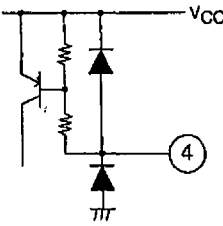
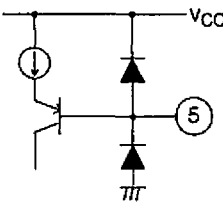
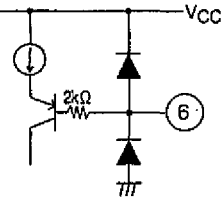
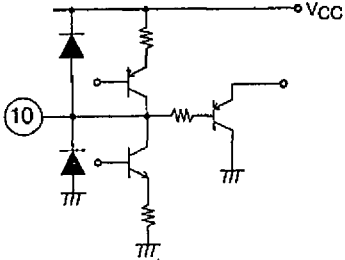
Pin Functions

Pin No.	Symbol	Pin voltage	Equivalent circuit diagram	Function
18 19 20 21 22 23	U_{IN}^+ U_{IN}^- V_{IN}^+ V_{IN}^- W_{IN}^+ W_{IN}^-	1.5 V min $V_{CC} - 1.0$ V max	 <p>A06536</p>	U phase Hall element input V phase Hall element input W phase Hall element input
24	HB	0.8 V typ ($I_H = 5$ mA)	 <p>A06537</p>	Minus side connection for providing the Hall bias current This pin becomes open in the stopped state, thus cutting the Hall bias current.
25 26 27	FG_{IN}^+ FG_{IN}^- FG_{OUT}	2.5 V	 <p>A06538</p>	<ul style="list-style-type: none"> FG amplifier plus input A 2.5-V reference voltage is generated internally. FG amplifier minus input FG amplifier output
28 1	I^+ I^-		 <p>A06539</p>	Index input
2	ID	L: 0.4 V max H: 4.5 V min	 <p>A06540</p>	Index output

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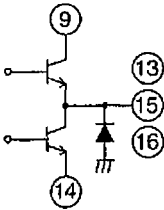
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Pin No.	Symbol	Pin voltage	Equivalent circuit diagram	Function
4	SS	L: 0.8 V max H: 3.5 V min		Start/stop mode switching This is an active-low input.
5	SL	L: 1.0 V max H: 3.5 V min		Rotational speed switching
6	CLK	L: 1.0 V max H: $V_{CC} - 1.0$ V min		Reference clock input A 1-MHz input frequency corresponds to speeds of 300 and 360 rpm.
7	GND			<ul style="list-style-type: none"> Ground This pin, pin 14, and the frame must all be grounded together.
8	V_{CC}			Power supply This voltage must be stabilized so that ripple and noise do not enter the IC.
9	R_f			Output current detection The output current is detected as a voltage by connecting the resistor R_f between this pin and V_{CC} . The current limiter operates by detecting the voltage on this pin.
10	D_O			Speed discriminator
11	F_C			Frequency characteristics compensation Current control system loop oscillation is prevented by connecting a capacitor between this pin and ground.

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Pin No.	Symbol	Pin voltage	Equivalent circuit diagram	Function
13 15 16	U_{OUT} V_{OUT} W_{OUT}			U phase output V phase output W phase output
14	P_{GND}			Output transistor ground connection

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